

**TERMINAL ASSIGNMENT**

## CMOS Hex Voltage-Level Shifter for TTL-to-CMOS or CMOS-to-CMOS Operation

High-Voltage Types (20-Volt Rating)

**Features:**

- Independence of power-supply sequence considerations— $V_{CC}$  can exceed  $V_{DD}$ ; input signals can exceed both  $V_{CC}$  and  $V_{DD}$
- Up and down level-shifting capability
- Shiftable input threshold for either CMOS or TTL compatibility
- Standardized symmetrical output characteristics
- 100% tested for quiescent current @ 20 V
- Maximum input current of 1  $\mu$ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- 5 V, 10 V, and 15 V parametric ratings
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

■ CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the  $V_{CC}$  logic level to the  $V_{DD}$  logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the  $V_{CC}$  HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

The CD4504B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and MT suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

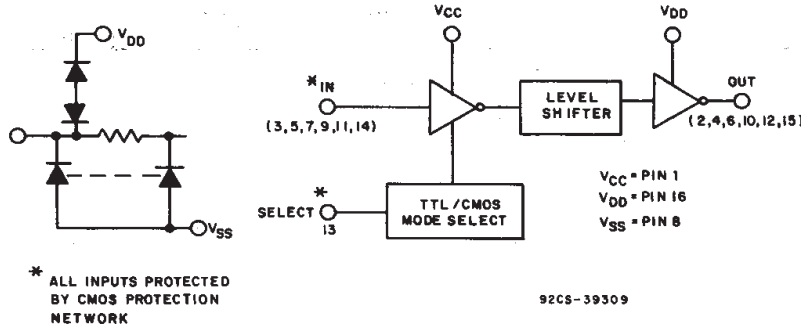


Fig. 1 - Functional diagram for CD4504B.

**MAXIMUM RATINGS, Absolute-Maximum Values:**

<b>DC SUPPLY-VOLTAGE RANGE, (<math>V_{DD}</math>)</b>	
Voltages referenced to $V_{SS}$ Terminal	-0.5V to +20V
<b>INPUT VOLTAGE RANGE, ALL INPUTS</b>	
	-0.5V to $V_{CC} + 0.5V$
<b>DC INPUT CURRENT, ANY ONE INPUT</b>	
	$\pm 10$ mA
<b>POWER DISSIPATION PER PACKAGE (<math>P_D</math>):</b>	
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$	500mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$ :	Derate Linearly at 12mW/ $^\circ\text{C}$ to 200mW
<b>DEVICE DISSIPATION PER OUTPUT TRANSISTOR -</b>	
FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
<b>OPERATING-TEMPERATURE RANGE (<math>T_A</math>)</b>	
	$-55^\circ\text{C}$ to $+125^\circ\text{C}$
<b>STORAGE TEMPERATURE RANGE (<math>T_{stg}</math>)</b>	
	$-85^\circ\text{C}$ to $+150^\circ\text{C}$
<b>LEAD TEMPERATURE (DURING SOLDERING):</b>	
At distance 1/16 $\pm$ 1/32 inch (1.59 $\pm$ 0.79mm) from case for 10s max	+265°C

3  
COMMERCIAL CMOS  
HIGH VOLTAGE ICs

# CD4504B Types

V<sub>GEN</sub>

## STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS				LIMITS AT INDICATED TEMPERATURES (°C)							UNITS	
	V <sub>O</sub> (V)	V <sub>IN</sub> (V)	V <sub>CC</sub> (V)	V <sub>DD</sub> (V)	-55	-40	+85	+125	+25				
									MIN	TYP	MAX		
Quiescent Device Current, I <sub>DD</sub> Max and I <sub>CC</sub> in CMOS-CMOS Mode	—	0,5	5	5	1.5	1.5	1.5	1.5	—	0.02	1.5	mA	
	—	0,10	5	10	2	2	2	2	—	0.02	2		
	—	0,15	5	15	4	4	120	120	—	0.02	4	μA	
	—	0,20	5	20	20	20	600	600	—	0.04	20		
Quiescent Device Current, I <sub>CC</sub> Max TTL-CMOS Mode	—	0,5	5	5	5	5	6	6	—	2.5	5	mA	
	—	0,10	5	10	5	5	6	6	—	2.5	5		
	—	0,15	5	15	5	5	6	6	—	2.5	5		
Output Low (Sink) Current, I <sub>OL</sub> Min	0.4	0.5	—	5	0.64	0.61	0.42	0.36	0.51	1	—	mA	
	0.5	0,10	—	10	1.6	1.5	1.1	0.9	1.3	2.6	—		
	1.5	0,15	—	15	4.2	4	2.8	2.4	3.4	6.8	—		
Output High (Source) Current, I <sub>OH</sub> Min	4.6	0,5	—	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA	
	2.5	0,5	—	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—		
	9.5	0,10	—	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—		
	13.5	0,15	—	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—		
Output Voltage: Low-Level, V <sub>OL</sub> Max	—	0,5	—	5	0.05				—	0	0.05	V	
	—	0,10	—	10	0.05				—	0	0.05		
	—	0,15	—	15	0.05				—	0	0.05		
Output Voltage: High-Level, V <sub>OH</sub> Min	—	0,5	—	5	4.95				4.95	5	—	V	
	—	0,10	—	10	9.95				9.95	10	—		
	—	0,15	—	15	14.95				14.95	15	—		
Input Low Voltage, V <sub>IL</sub> Max Note 1	TTL-CMOS	1	—	5	10	0.8				—	—	0.8	V
	TTL-CMOS	1	—	5	15	0.8				—	—	0.8	
	CMOS-CMOS	1	—	5	10	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	5	15	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	10	15	3				—	—	3	
Input High Voltage, V <sub>IH</sub> Min Note 1	TTL-CMOS	9	—	5	10	2				2	—	—	V
	TTL-CMOS	13.5	—	5	15	2				2	—	—	
	CMOS-CMOS	9	—	5	10	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	5	15	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	10	15	7				7	—	—	
Input Current, I <sub>IN</sub> Max	—	0,18	—	18	±0.1	±0.1	±1	±1	—	±10 <sup>-5</sup>	±0.1	μA	

Note 1: Applies to the 6 input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

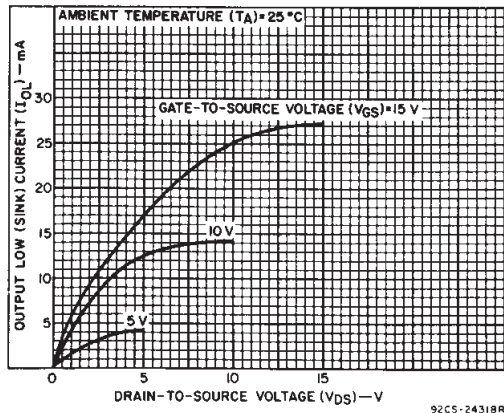


Fig. 2 - Typical output low (sink) current characteristics.

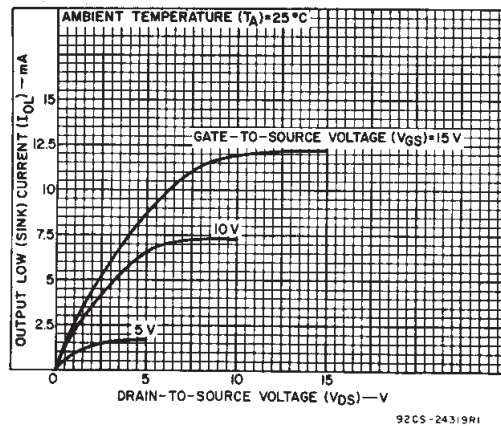
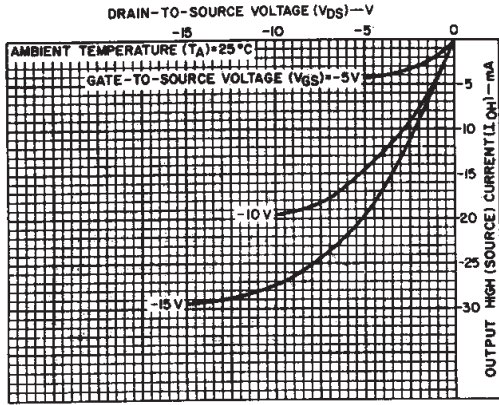


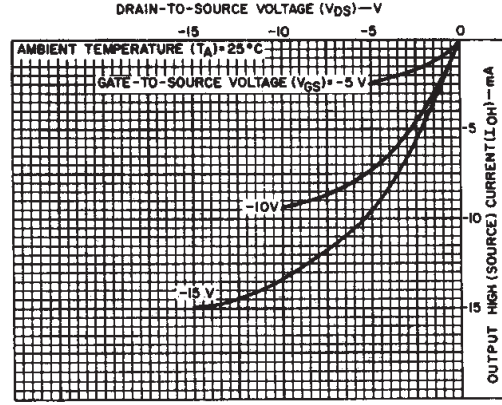
Fig. 3 - Minimum output low (sink) current characteristics.

# CD4504B Types



92CS-24320R3

Fig. 4 - Typical output high (source) current characteristics.



92CS-24321R2

Fig. 5 - Minimum output high (source) current characteristics.

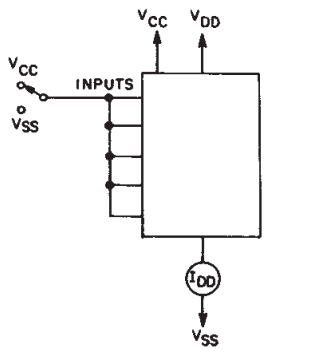
## RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V <sub>DD</sub> (V)	LIMITS		UNITS
		Min.	Max.	
Supply-Voltage Range (For T <sub>A</sub> = Full Package-Temperature Range)	—	5	18	V

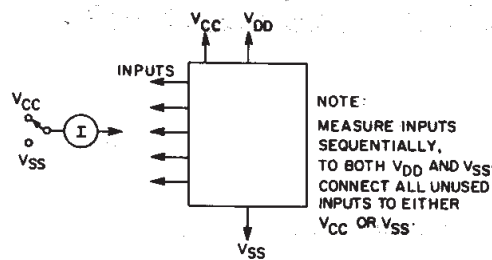
## DYNAMIC ELECTRICAL CHARACTERISTICS, At T<sub>A</sub> = 25°C; Input t<sub>r</sub>, t<sub>f</sub> = 20 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 200 Ω

CHARACTERISTIC	SHIFTING MODE	V <sub>CC</sub> (V)	V <sub>DD</sub> (V)	LIMITS		UNITS
				TYP.	MAX.	
Propagation Delay: High-to-Low, t <sub>PHL</sub>	TTL to CMOS V <sub>DD</sub> > V <sub>CC</sub>	5	10	140	280	ns
	CMOS to CMOS V <sub>DD</sub> > V <sub>CC</sub>	5	15	140	280	
	CMOS to CMOS V <sub>CC</sub> > V <sub>DD</sub>	5	10	120	240	
		5	15	120	240	
		10	15	70	140	
		10	5	275	550	
		15	5	275	550	
		15	10	70	140	
Low-to-High, t <sub>PLH</sub>	TTL to CMOS V <sub>DD</sub> > V <sub>CC</sub>	5	10	140	280	ns
	CMOS to CMOS V <sub>DD</sub> > V <sub>CC</sub>	5	15	140	280	
	CMOS to CMOS V <sub>CC</sub> > V <sub>DD</sub>	5	10	120	240	
		5	15	120	240	
		10	15	70	140	
		10	5	200	400	
		15	5	200	400	
		15	10	60	120	
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>	All Modes		5	100	200	ns
			10	50	100	
			15	40	80	
Input Capacitance, C <sub>IN</sub>	Any Input			5	7.5	pF



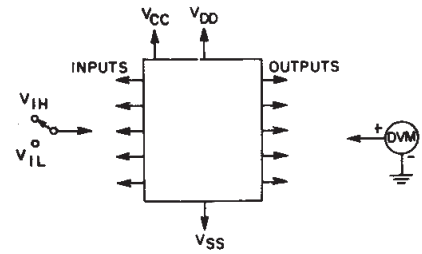
92CS-29452

Fig. 6 - Quiescent device current.



92CS-29454

Fig. 7 - Input current.



NOTE:  
TEST ANY COMBINATION  
OF INPUTS

92CS-29453

Fig. 8 - Input voltage.

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# CD4504B Types

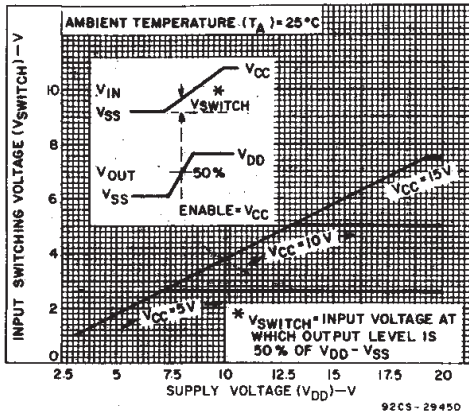


Fig. 9 - Typical input switching as a function of high-level supply voltage. (SELECT at  $V_{CC}$ -CMOS mode).

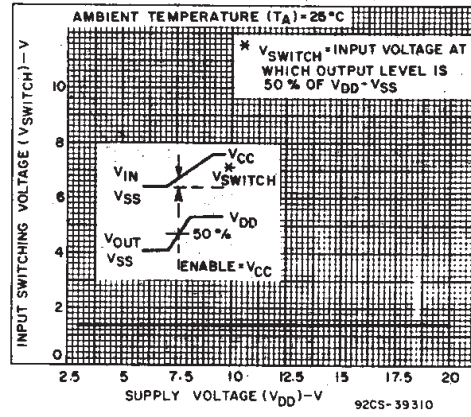


Fig. 10 - Typical input switching as a function of high-level supply voltage (SELECT at  $V_{SS}$ -TTL mode).

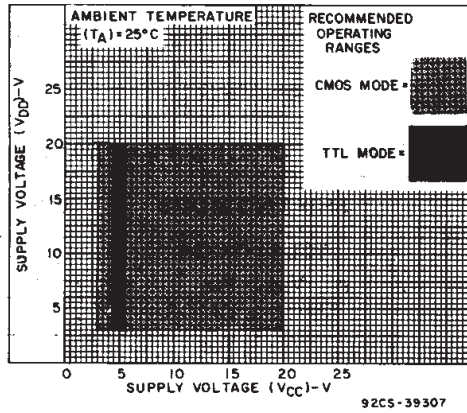
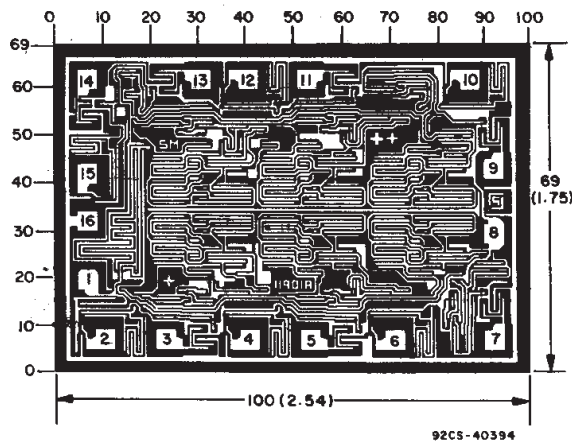


Fig. 11 - High-level supply voltage vs. low-level supply voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

Dimensions and pad layout for CD4504BH.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD4504BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4504BE	<a href="#">Samples</a>
CD4504BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4504BE	<a href="#">Samples</a>
CD4504BF3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4504BF3A	<a href="#">Samples</a>
CD4504BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BM96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BME4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BMG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM	<a href="#">Samples</a>
CD4504BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	<a href="#">Samples</a>
CD4504BPWE4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	<a href="#">Samples</a>
CD4504BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**OTHER QUALIFIED VERSIONS OF CD4504B, CD4504B-MIL :**

- Catalog : [CD4504B](#)
- Enhanced Product : [CD4504B-EP](#), [CD4504B-EP](#)
- Military : [CD4504B-MIL](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4504BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4504BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4504BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4504BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0



**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BM	D	SOIC	16	40	507	8	3940	4.32
CD4504BME4	D	SOIC	16	40	507	8	3940	4.32
CD4504BMG4	D	SOIC	16	40	507	8	3940	4.32
CD4504BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPWE4	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



4220204/A 02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

J (R-GDIP-T\*\*)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice.
  - This package is hermetically sealed with a ceramic lid using glass frit.
  - Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
  - Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.





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